Supporting Information for:

A novel Sn₂Nb₂O₇/defective carbon nitride heterojunction photocatalyst:

preparation and application for photocatalytic oxytetracycline removal.

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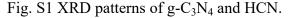
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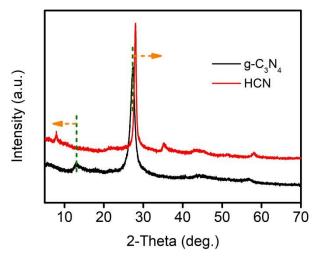
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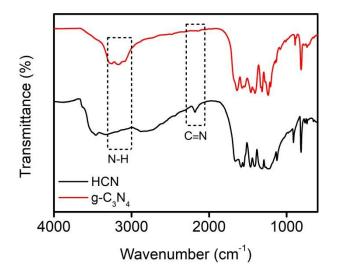
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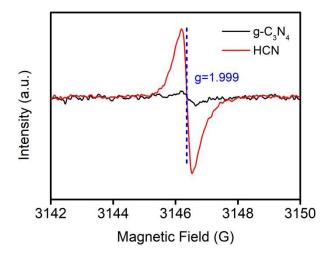
Clearly, it can be seen that the crystalline of HCN was improved after the modification of KSCN and acid. Meanwhile, the diffraction peaks of HCN shifted from 13.0° to 8.0° and 27.3° to 28.1° in comparison with g-C₃N₄, indicating a larger in-plane arrangement distance and a compacted packing of heptazine layers.^{1,2}

Fig. S2 FT-IR spectra of g-C₃N₄ and HCN.



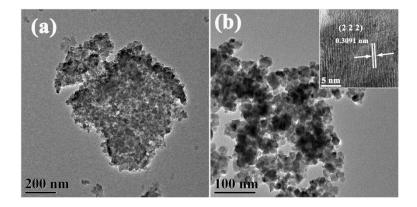
The additional peak appeared at 2180 cm⁻¹ in HCN can be related to the formation of -C=N, deriving from the residual thiocyanogen groups.³ Meanwhile, the peak intensity of N-H in HCN sample weakened compared with g-C₃N₄, suggesting that the generation of -C=N groups was from the deprotonation of NH_x group.⁴ Based on the above analysis, cyano- group was introduced in HCN, which could act as defective centers to boost the separation of photoinduced carriers.

Fig. S3 EPR spectra of $g-C_3N_4$ and HCN.



According to previous report, an EPR signal (g = 1.999) belonged to unpaired electrons on the sp²-carbon atoms of aromatic rings within π -bonded nanosized clusters, revealing the formation of nitrogen vacancies in carbon nitride.⁵ A higher EPR signal intensity of HCN was attributed to the introduction of cyano- groups, then accelerating the generation of unpaired electrons.

Fig. S4 TEM image of HCN (a) and $Sn_2Nb_2O_7$ (b).



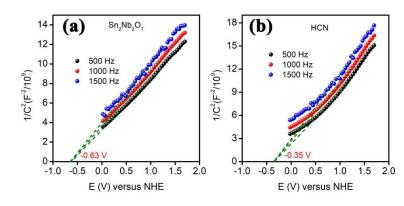
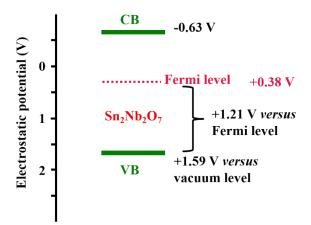


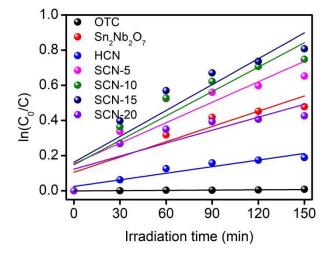
Fig. S5 Mott-Schottky plots of $Sn_2Nb_2O_7$ (a) and HCN (b).

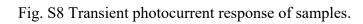
Fig. S6 Electronic structure of Sn₂Nb₂O₇.

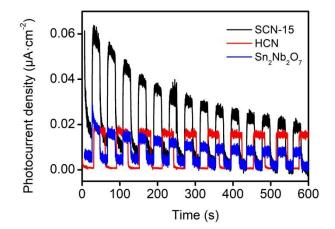


The Fermi levels of $Sn_2Nb_2O_7$ and HCN were calculated by the results of VB-XPS and valence band energy results. As shown in Fig. S6, the VBM of $Sn_2Nb_2O_7$ versus vacuum level and Fermi level was 1.59 V and 1.21 V, respectively. The Fermi level of $Sn_2Nb_2O_7$ was calculated to be 0.38 V by subtracting the 1.21 V with 1.59 V. Similarly, the Fermi level of HCN was calculated to be 0.12 V.⁶

Fig. S7 The relationship between $\ln (C_0/C)$ and irradiation time for the degradation of OTC over all samples.







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